

Substitute for form 1449A/PTO  <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> <i>(Use as many sheets as necessary)</i>	<i>Complete if Known</i>	
	<b>Application Number</b>	10/572,524
	<b>Filing Date</b>	March 20, 2006
	<b>First Named Inventor</b>	Kang, Xuejun
	<b>Group Art Unit</b>	Not Yet Assigned
	<b>Examiner Name</b>	Unknown
Sheet 1 of 1		Attorney Docket No: 7989P001

US PATENT DOCUMENTS					
Examiner Initial *	Cite No <sup>1</sup>	USP Document Number	Publication or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear

FOREIGN PATENT DOCUMENTS						
Examiner Initials *	Cite No <sup>1</sup>	Foreign Patent Document Country Code/Number/Kind Code (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>2</sup>

OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS			
Examiner Initials *	Cite No <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
		CHU, CHEN F., et al., "Comparison of p-Side Down and p-Side Up GaN Light-Emitting Diodes Fabricated by Laser Lift-Off", <u>Japan Journal of Applied Physics</u> , Vol. 42, (02/15/2003), 147-150	
		LI, W H., et al., "Electrochemical deposition of Copper on patterned Cu/Ta(N)SiO2 surfaces for super filling of sub-micron features", <u>Journal of Applied Electrochemistry</u> , Vol. 31, (2001), 1395-1397	

EXAMINER

DATE CONSIDERED